## NSN 5962-01-540-5851

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Operating Tempurature Range:
+0.0/+70.0 degrees celsius
Features Provided:
3-state output
Inclosure Material:
Metal and oxide
Inclosure Configuration:
Pin grid array
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Current Rating Per Characteristic:
100.00 amperes forward current, nonrepetitive, peak total value microamperes
Product Name:
Fat page mode dram
Voltage Rating And Type Per Characteristic:
5.0 volts power source
Memory Device Type:
Ram
Memory Capacity:
128k x 8
Terminal Type And Quantity:
26 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0